

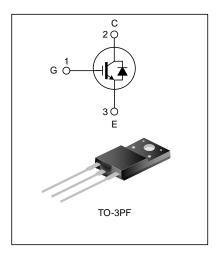
40A, 600V FIELD STOP IGBT

DESCRIPTION

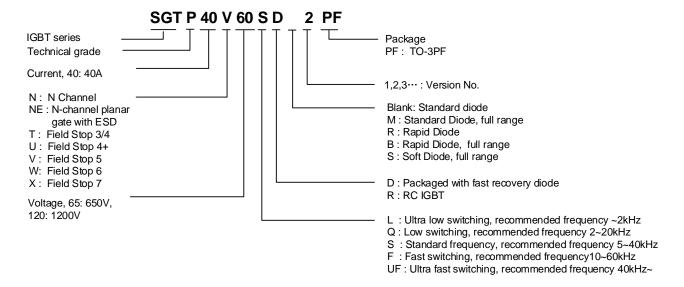
The SGTP40V60SD2PF field stop IGBT adopts Silan Field Stop V technology, features low conduction loss and switching loss. This device is applicable to photovoltaic, UPS, SMPS, and PFC fields.

FEATURES

- 40A, 600V, V_{CE(sat)(typ.)}=1.35V@I_C=40A
- Low conduction loss
- Ultra-fast switching
- High input impedance
- T_{Jmax}=175°C



NOMENCLATURE



ORDERING INFORMATION

Part No.	Package	Marking	Marking Hazardous Substance Control	
SGTP40V60SD2PF	D2PF TO-3PF 40V60SD2		Halogen free	Tube

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ABSOLUTE MAXIMUM RATINGS (UNLESS OTHERWISE NOTED, Tc=25°C)

Charac	teristics	Symbol	Ratings	Unit
Collector to Emitte	r Voltage	V _{CE}	600	V
Gate to Emitter Vo	tter Voltage V _{GE} ±20		±20	V
Transient Gate to I (t _p ≤10µs, D<0.010)	· ·	V _{GE}	±30	V
Collector Current	T _C =25°C	,	80	Α
	T _C =100°C	- I _C	40	A
Pulsed Collector C	Pulsed Collector Current		160	Α
Diada Current	T _C =25°C		10	۸
Diode Current	T _C =100°C	─ I _F	5	А
Diode Pulsed Curr	ent	I _{FM}	15	Α
Power Dissipation (T _C =25°C)		P _D	60	W
Operating Junction Temperature		TJ	-40∼+175	°C
Storage Temperature Range		T _{stg}	-55∼+150	°C

THERMAL CHARACTERISTICS

Characteristics	Symbol	Test conditions	Min.	Тур.	Max.	Unit
Thermal Resistance, Junction to Case	R _{eJC}				2.5	°C/W
(IGBT)	1,630			 	2.0	C/VV
Thermal Resistance, Junction to Case	D				F 2	0000
(FRD)	$R_{ heta JC}$				5.3	°C/W
Thermal Resistance, Junction to	В				40	0000
Ambient (IGBT)	$R_{\theta JA}$				40	°C/W
Soldering temperature (in line)	T _{sold}	15 ⁺² ₋₀ sec, 1time			260	°C

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ELECTRICAL CHARACTERISTICS OF IGBT (UNLESS OTHERWISE NOTED, Tc=25°C)

Characteristics	Symbol	Test conditions	Min.	Тур.	Max.	Unit
Collector to Emitter	D) (\/ 0\/ 050\	600			
Breakdown Voltage	BV _{CE}	$V_{GE}=0V$, $I_{C}=250\mu A$	600			V
C-E Leakage Current	I _{CES}	V _{CE} =600V, V _{GE} =0V			100	μA
G-E Leakage Current	I _{GES}	V _{GE} =20V, V _{CE} =0V			±100	nA
G-E Threshold Voltage	V _{GE(th)}	I _C =250μA, V _{CE} =V _{GE}	3.2	4.5	5.8	V
Collector to Emitter		I _C =40A, V _{GE} =15V, T _C =25°C		1.35	1.7	V
Saturation Voltage	V _{CE(sat)}	I _C =40A, V _{GE} =15V, T _C =175°C		1.55		V
Input Capacitance	C _{ies}	V _{CE} =30V		3018		
Output Capacitance	C _{oes}	V _{GE} =0V		53		pF
Reverse Transfer Capacitance	C _{res}	f=1MHz		10		
Turn-On Delay Time	T _{d(on)}			39		ns
Rise Time	Tr	V _{CE} =400V		46		
Turn-Off Delay Time	T _{d(off)}	I _C =40A		150		
Fall Time	T _f	R_g =10 Ω - V_{GE} =15 V - inductive load - T_{C} =25 $^{\circ}$ C		25		
Turn-On Switching Loss	E _{on}			0.88		mJ
Turn-Off Switching Loss	E _{off}			0.62		
Total Switching Loss	E _{st}	1 1C=25 C		1.50		
Turn-On Delay Time	T _{d(on)}			37		
Rise Time	Tr	V _{CE} =400V		19		
Turn-Off Delay Time	T _{d(off)}	I _C =20A		156		ns
Fall Time	T _f	$R_g=10\Omega$ $V_{GE}=15V$ inductive load $T_{C}=25^{\circ}C$		33		
Turn-On Switching Loss	Eon			0.31		
Turn-Off Switching Loss	E _{off}			0.32		mJ
Total Switching Loss	E _{st}			0.63		
Total Gate Charge	Qg	V _{CE} =480V, I _C =40A, V _{GE} =15V		110		
Gate to Emitter Charge	Q _{ge}			21		nC
Gate to Collector Charge	Q _{gc}			29		

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ELECTRICAL CHARACTERISTICS OF FRD (UNLESS OTHERWISE NOTED, Tc=25°C)

Characteristics	Symbol	Test conditions	Min.	Тур.	Max.	Unit
Diede Femuerd Veltere	V _{FM}	I _F =5A, T _C =25°C		1.4	2.0	V
Diode Forward Voltage		I _F =5A, T _C =175°C		1.2		
Diode Reverse Recovery Time	Trr	L EA dL /dt 100A/us \/ E0\/		35		ns
Diode Reverse Recovery Charge	Q _{rr}	I_{ES} =5A, dI_{ES} / dt =100A/ μ s, V_R =50V, I_C =25°C		42		nC
Diode Reverse Recovery Current	Irm	10=20°C		2.4		Α

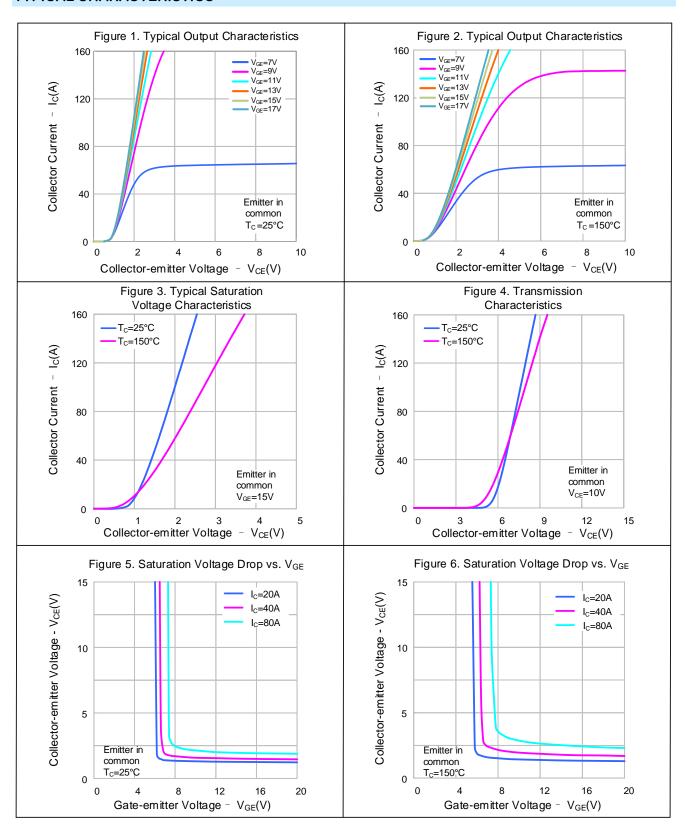
ELECTRICAL CHARACTERISTICS OF IGBT (UNLESS OTHERWISE NOTED, T_C=150°C)

Characteristics	Symbol	Test conditions	Min.	Тур.	Max.	Unit
Turn-On Delay Time	T _{d(on)}	V 400V		38		
Rise Time	Tr	V _{CE} =400V		43		20
Turn-Off Delay Time	T _{d(off)}	I _C =40A		187	-	ns
Fall Time	Tf	$R_g=10\Omega$ $V_{GE}=15V$		35		
Turn-On Switching Loss	E _{on}	inductive load		0.92		
Turn-Off Switching Loss	E _{off}			0.93		mJ
Total Switching Loss	E _{st}	T _C =150°C		1.85		
Turn-On Delay Time	T _{d(on)}	$V_{\text{CE}} = 400V$ $I_{\text{C}} = 20A$ $R_{g} = 10\Omega$ $V_{\text{GE}} = 15V$ inductive load $T_{\text{C}} = 150^{\circ}\text{C}$		36		
Rise Time	Tr			18		20
Turn-Off Delay Time	T _{d(off)}			201		ns
Fall Time	T _f			43		
Turn-On Switching Loss	E _{on}			0.33		
Turn-Off Switching Loss	E _{off}			0.43		mJ
Total Switching Loss	E _{st}			0.76		

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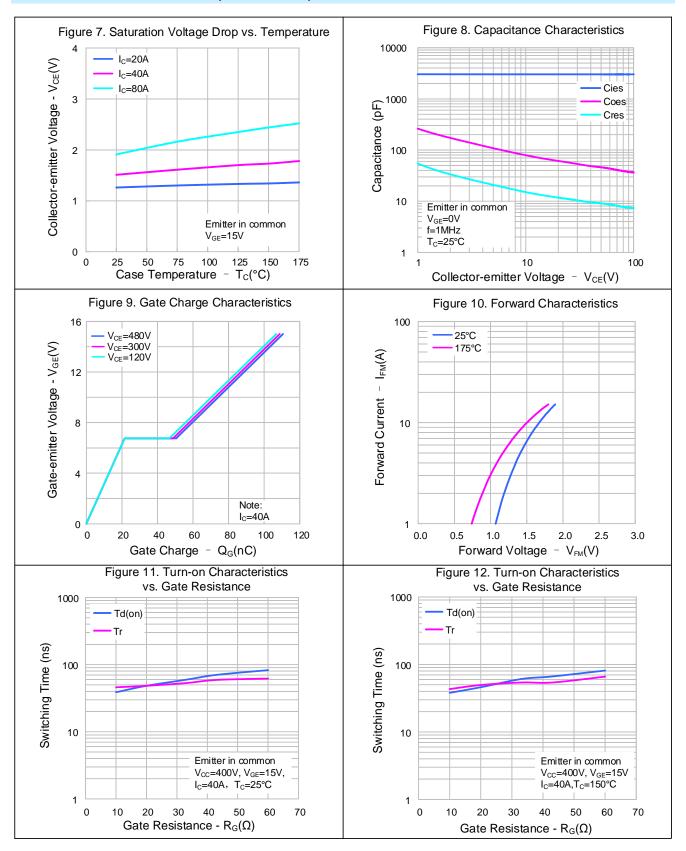
TYPICAL CHARACTERISTICS



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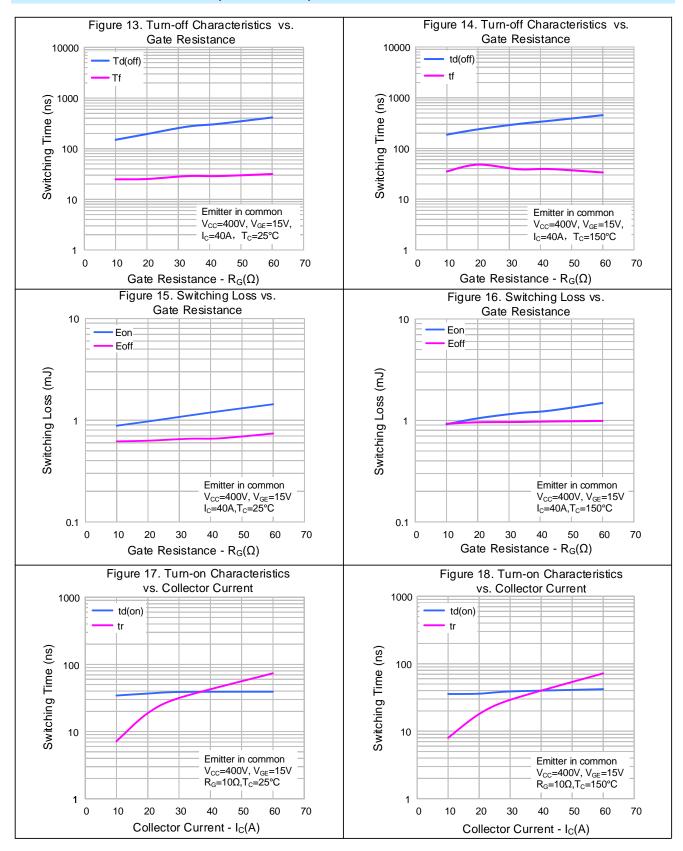
TYPICAL CHARACTERISTICS (CONTINUED)



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TYPICAL CHARACTERISTICS (CONTINUED)

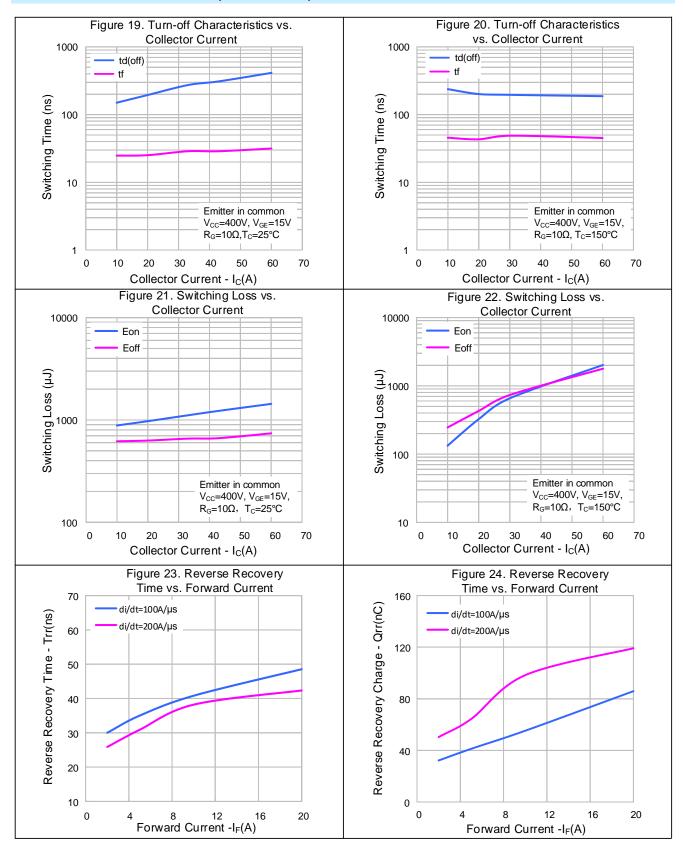


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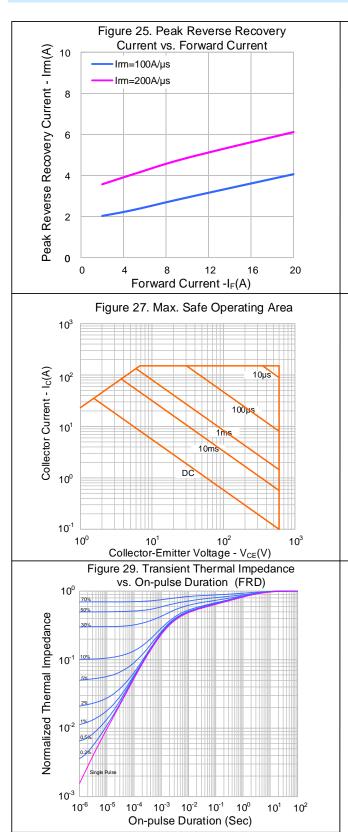
TYPICAL CHARACTERISTICS (CONTINUED)

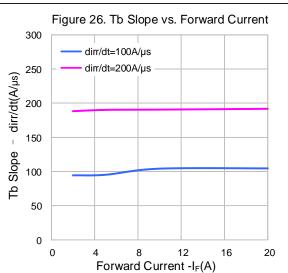


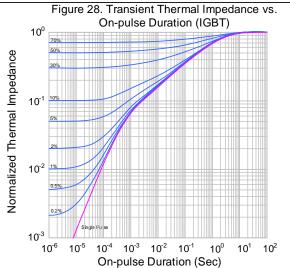
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TYPICAL CHARACTERISTICS (CONTINUED)



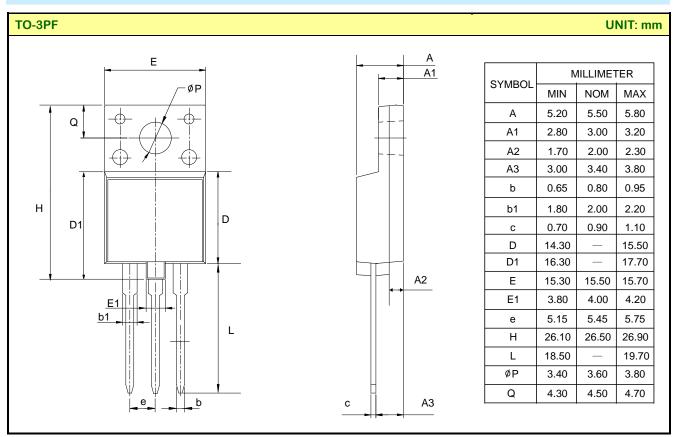




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PACKAGE OUTLINE





MOS DEVICES OPERATE NOTES:

Electrostatic charges may exist in many things. Please take following preventive measures to prevent effectively the MOS electric circuit as a result of the damage which is caused by discharge:

- The operator must put on wrist strap which should be earthed to against electrostatic.
- Equipment cases should be earthed.
- All tools used during assembly, including soldering tools and solder baths, must be earthed.
- MOS devices should be packed in antistatic/conductive containers for transportation.

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Important notice:

- Silan reserves the right to make changes of this instruction without notice.
- Customers should obtain the latest relevant information when purchasing and should verify whether such information is latest and complete. Please read this instruction and application manual and related materials carefully before using products, including the circuit operation precautions, etc.
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- Please use and apply product in compliance with all applicable laws and regulations, including but not limited to trade control regulations etc. The product is civil electronic product, please do not use it in non-civil fields.
- 8. Product promotion is endless, our company will wholeheartedly provide customers with better products!
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1.0 Rev.: Revision History:

First release

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